

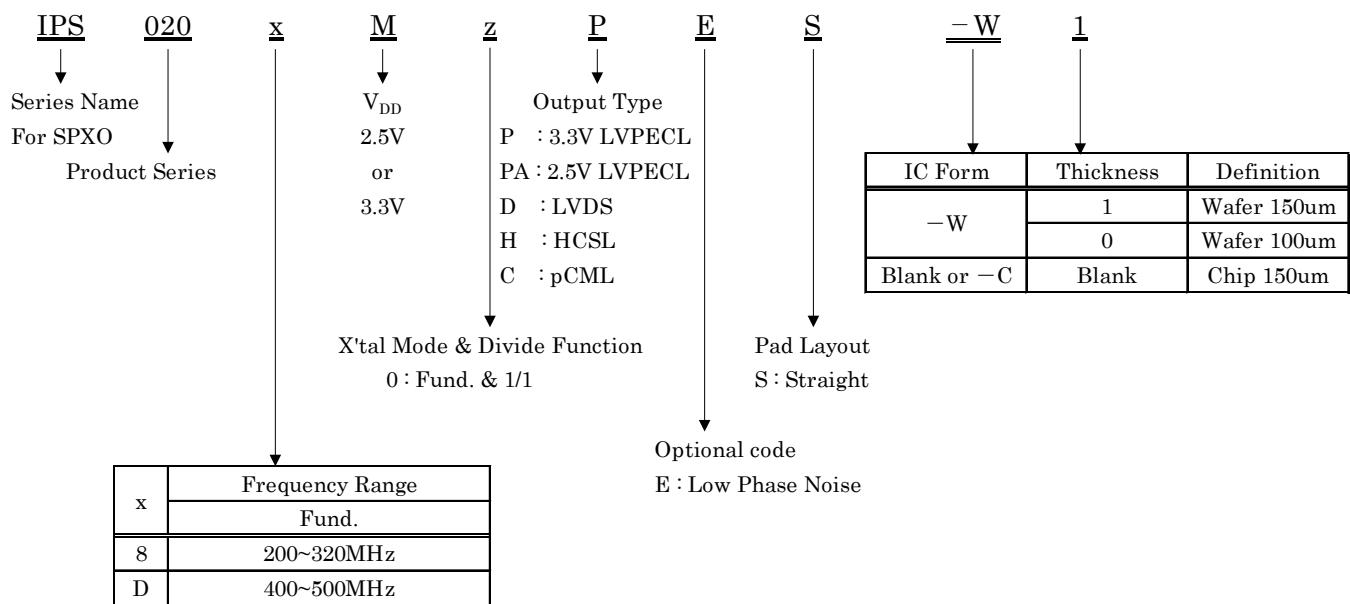
■ Description

IPS020 High Frequency Type is the IC for differential output SPXO corresponding to the high frequency from 200MHz to 500MHz, and operation voltage is 2.375V minimum.

■ Features

- Operation temperature : -40°C~125°C
- Power supply voltage : 2.375V~3.63V
- Standby function : Oscillation stop
- Crystal frequency : 200MHz~500MHz
- Output : LVPECL / LVDS / HCSL / pCML(HDLVDS)
- Crystal mode : Fundamental
- Small chip size : 0.65mm × 0.75mm
- Pad layout : Straight type
- Duty cycle : Within 50%±5%

1. Part number rule



The contents of this sheet are subject to change without notice.

2. Series

Part Number	Output	Crystal Frequency (MHz)			Divide	Output Frequency (MHz)		Remarks
		Mode	Min.	Max.		Min.	Max.	
IPS020 8 M 0 P E S	LVPECL	Fund.	200	320	1/1	200	320	V _{DD} =3.3V±10%
IPS020 D M 0 P E S			400	500		400	500	
IPS020 8 M 0 P A E S	LVPECL	Fund.	200	320	1/1	200	320	V _{DD} =2.5V±5%
IPS020 D M 0 P A E S			400	500		400	500	
IPS020 8 M 0 D E S	LVDS	Fund.	200	320	1/1	200	320	
IPS020 D M 0 D E S			400	500		400	500	
IPS020 8 M 0 H E S	HCSL	Fund.	200	320	1/1	200	320	
IPS020 8 M 0 C E S	pCML	Fund.	200	320	1/1	200	320	

3. Absolute Maximum Ratings

V_{SS}=0V, Ta=25°C± 2°C

Parameter	Symbol	Condition	Ratings		
			Min	Max	Unit
Supply Voltage	V _{DD}		V _{SS} -0.5	5.0	V
Input Voltage	V _{IN}	All Input Pin	V _{SS} -0.5	V _{DD} +0.5	V
Output Voltage	V _{OUT}		V _{SS} -0.5	V _{DD} +0.5	V
Output Current	I _{OUT}			25	mA
Junction Temperature	T _j		-55	150	°C
Storage Temperature	T _{stg}		-55	125	°C

4. Recommended Operating Condition

V_{SS}=0V, Ta=-40°C~125°C

Parameter	Symbol	Condition	Min	Typ	Max	Unit	Note
Supply Voltage	V _{DD}	2.5V LVPECL	2.375	2.50	2.625	V	V _{DD}
		LVDS, HCSL	2.375	3.30	3.63		
		3.3V LVPECL, pCML	2.97	3.30	3.63		
“H” Input Voltage	V _{IH}		V _{DD} ×0.7			V	CE
“L” Input Voltage	V _{IL}				V _{DD} ×0.3	V	CE
Input Voltage	V _{IN}		V _{SS}		V _{DD}	V	CE
Output Load Resistance	RL	LVPECL ≈1	49.5	50.0	50.5	Ω	OUT
		LVDS ≈2	99	100	101		
		HCSL ≈3	49.5	50.0	50.5		
		pCML ≈4	80	100	120		
Ambient Temperature	T _{opt}		-40		125	°C	

This IC has enough immunity against ESD and Latch-up, but handle with care.

※1 Terminate to V_{DD}-2.0V ※2 Between OUT and OUTN ※3 To GND and Rs=0Ω

※4 Between OUT and OUTN, AC coupling

5. Electrical Specification

5-1 LVPECL Output (V_{DD}=3.3V Operation)

5-1-1 DC Characteristics

Unless otherwise stated, V_{DD}=2.97V~3.63V, V_{SS}=0V, Ta=-40°C~125°C

Parameter	Symbol	Condition	Specification			Unit	
			Min	Typ	Max		
Output leak current	I _Z	CE=0.3V			10	μA	
“L” input current	I _{IL}	V _{IN} =V _{SS}		-10		μA	
“H” output voltage	V _{OH}	RL=50Ω(Terminated to V _{DD} -2.0V) CE=Open, OUT/OUTN	V _{DD}	V _{DD}	V _{DD}	V	
“L” output voltage	V _{OL}		-1.025	-0.950	-0.880		
Current consumption	I _{DD}	V _{DD} =3.3V CE=Open RL=50Ω (Terminated to V _{DD} -2.0V)	IPS0208M0PES F0=314.68MHz		40.0	60.0	mA
Current consumption at oscillation stop	I _{DDD}	CE≤0.3V	IPS020DM0PES F0=500MHz		42.0	63.0	
					100	300	uA

5-1-2 Switching Characteristics

Unless otherwise stated, $V_{DD}=2.97V \sim 3.63V$, $V_{SS}=0V$, $T_a=-40^{\circ}C \sim 125^{\circ}C$

Parameter	Symbol	Condition	Specification			Unit
			Min	Typ	Max	
Oscillation start up time	T_{start}				2.0	ms
Output Disable Time	T_{plz}				200	ns
Output Enable Time	T_{pzl}				2.0	ms
Rise time / Fall time	T_r / T_f	20%~80% V_{opp}		0.25	0.40	ns
Output Duty Ratio	Duty	1/2 V_{opp} point	45		55	%
Output Swing	V_{opp}		0.4			V
Freq. V_{DD} deviation	F_{vst}	$V_{DD}=3.3V \pm 10\%$	$V_{DD}=3.3V \pm 10\%$		± 2.0	ppm
			$V_{DD}=3.3V \pm 10\%$		± 3.0	

5-2 LVPECL Output ($V_{DD}=2.5V$ Operation)

5-2-1 DC Characteristics

Unless otherwise stated, $V_{DD}=2.375V \sim 2.625V$, $V_{SS}=0V$, $T_a=-40^{\circ}C \sim 125^{\circ}C$

Parameter	Symbol	Condition	Specification			Unit
			Min	Typ	Max	
Output leak current	I_Z	$CE=0.3V$			10	μA
"L" input current	I_{IL}	$V_{IN}=V_{SS}$		-10		μA
"H" output voltage	V_{OH}	$RL=50\Omega$ (Terminated to $V_{DD}-2.0V$) $CE=Open$, OUT/OUTN	V_{DD}	V_{DD}	V_{DD}	V
"L" output voltage	V_{OL}		-1.105	-0.985	-0.870	
Current consumption	I_{DD}	$V_{DD}=2.5V$ $CE=Open$ $RL=50\Omega$ (Terminated to $V_{DD}-2.0V$)	V_{DD}	V_{DD}	V_{DD}	mA
Current consumption at oscillation stop	I_{DDD}	$CE \leq 0.3V$	IPS0208M0PAES $F_0=314.68MHz$	36.0	54.0	
			IPS020DM0PAES $F_0=500MHz$	39.0	59.0	
				100	300	μA



INTERCHIP CORPORATION

IPS020 series IC 【High Freq. Type】
Differential Output SPXO

5-2-2 Switching Characteristics

Unless otherwise stated, V_{DD}=2.375V~2.625V, V_{SS}=0V, Ta=-40°C~125°C

Parameter	Symbol	Condition	Specification			Unit
			Min	Typ	Max	
Oscillation start up time	Tstart				2.0	ms
Output Disable Time	Tplz				200	ns
Output Enable Time	Tpzl				2.0	ms
Rise time / Fall time	Tr / Tf	20%~80% V _{OPP}		0.25	0.40	ns
Output Duty Ratio	Duty	1/2V _{OPP} point	45		55	%
Output Swing	V _{OPP}		0.4			V
Freq. V _{DD} deviation	Fvst	V _{DD} =2.5V±5%	IPS0208M		±2.0	ppm
			IPS020DM		±5.0	

5-3 LVDS Output

5-3-1 DC Characteristics

Unless otherwise stated, V_{DD}=2.375V~3.63V, V_{SS}=0V, Ta=-40°C~125°C

Parameter	Symbol	Condition	Specification			Unit
			Min	Typ	Max	
Output leak current	I _Z	C _E =0.3V			10	µA
“L” input current	I _{IL}	V _{IN} =V _{SS}		-10		µA
“H” output voltage	V _{OH}	RL=100Ω(Between OUT & OUTN) C _E =Open, OUT/OUTN		1.43	1.60	V
“L” output voltage	V _{OL}		0.90	1.10		V
Differential voltage	V _{OD}		247	330	454	mV
Differential voltage deviation	ΔV _{OD}				50	mV
Offset voltage	V _{OS}		1.125	1.250	1.375	V
Offset voltage deviation	ΔV _{OS}				50	mV
Current consumption	I _{DD}	V _{DD} =3.3V C _E =Open RL=100Ω (Between OUT & OUTN)	IPS0208M0DES F ₀ =314.68MHz		15.0	30.0
			IPS020DM0DES F ₀ =500MHz		18.0	36.0
Current consumption at oscillation stop	I _{DDD}	C _E ≤0.3V		100	300	uA

5-3-2 Switching Characteristics

Unless otherwise stated, $V_{DD}=2.375V\sim3.63V$, $V_{SS}=0V$, $T_a=-40^{\circ}C\sim125^{\circ}C$

Parameter	Symbol	Condition	Specification			Unit
			Min	Typ	Max	
Oscillation start up time	Tstart				2.0	ms
Output Disable Time	Tplz				200	ns
Output Enable Time	Tpzl				2.0	ms
Rise time / Fall time	Tr / Tf	20%~80% Vopp			0.40	ns
Output Duty Ratio	Duty	1/2Vopp point	45		55	%
Output Swing	Vopp		0.25			V
Freq. V_{DD} deviation	Fvst	$V_{DD}=3.3V\pm10\%$	IPS0208M		±2.0	ppm
			IPS0208D		±3.0	
		$V_{DD}=2.5V\pm5\%$	IPS0208M		±2.0	
			IPS0208D		±5.0	

5-4 HCSL Output

5-4-1 DC Characteristics

Unless otherwise stated, $V_{DD}=2.375V\sim3.63V$, $V_{SS}=0V$, $T_a=-40^{\circ}C\sim125^{\circ}C$

Parameter	Symbol	Condition	Specification			Unit
			Min	Typ	Max	
Output leak current	I _Z	CE=0.3V			10	μA
"L" input current	I _{IL}	V _{IN} =V _{SS}		-10		μA
"H" output voltage	V _{OH}	RL=50Ω(To GND), Rs=0Ω CE=Open, OUT/OUTN	550		900	mV
"L" output voltage	V _{OL}		-150		150	mV
Current consumption	I _{DD}	V _{DD} =3.3V CE=Open RL=50Ω (To GND) Rs=0Ω	IPS0208M0HES F0=314.68MHz		26.0	39.0
Current consumption at oscillation stop	I _{DDDD}	CE≤0.3V		100	300	uA

5-4-2 Switching Characteristics

Unless otherwise stated, $V_{DD}=2.375V\sim3.63V$, $V_{SS}=0V$, $T_a=-40^{\circ}C\sim125^{\circ}C$

Parameter	Symbol	Condition	Specification			Unit
			Min	Typ	Max	
Oscillation start up time	Tstart				2.0	ms
Output Disable Time	Tplz				200	ns
Output Enable Time	Tpzl				2.0	ms
Rise time / Fall time	Tr / Tf	20%~80% Vopp		0.30	0.50	ns
Output Duty Ratio	Duty	1/2Vopp point	45		55	%
Output Swing	Vopp		0.55			V
Freq. VDD deviation	Fvst	V _{DD} =3.3V±10%			±2.0	ppm
		V _{DD} =2.5V±5%			±2.0	

5-5 pCML Output

5-5-1 DC Characteristics

Unless otherwise stated, $V_{DD}=2.97V\sim3.63V$, $V_{SS}=0V$, $T_a=-40^{\circ}C\sim125^{\circ}C$

Parameter	Symbol	Condition	Specification			Unit
			Min	Typ	Max	
Output leak current	I _Z	CE=0.3V			10	µA
“L” input current	I _{IL}	V _{IN} =V _{SS}		-10		µA
Current consumption	I _{DD}	V _{DD} =3.3V CE=Open RL=100Ω (Between OUT & OUTN) AC Coupling	IPS0208M0CES F0=314.68MHz	18.5	37.0	mA
Current consumption at oscillation stop	I _{DDD}	CE≤0.3V		100	300	uA

5-5-2 Switching Characteristics

Unless otherwise stated, $V_{DD}=2.97V\sim3.63V$, $V_{SS}=0V$, $T_a=-40^{\circ}C\sim125^{\circ}C$

Parameter	Symbol	Condition	Specification			Unit
			Min	Typ	Max	
Oscillation start up time	Tstart				2.0	ms
Output Disable Time	Tplz				200	ns
Output Enable Time	Tpzl				2.0	ms
Rise time / Fall time	Tr / Tf	20%~80% Vopp		0.25	0.35	ns
Output Duty Ratio	Duty	1/2Vopp point	45		55	%
Output Swing	Vopp		0.60			V
Freq. VDD deviation	Fvst	V _{DD} =3.3V±10%			±2.0	ppm

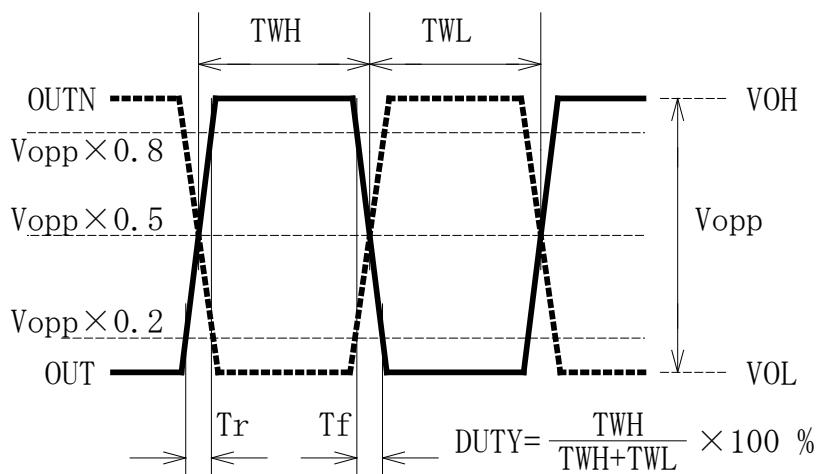


Fig. 5-1 Output Wave Form (Duty, Tr, Tf, VOH, VOL, VOPP) of LVPEL & HCSL

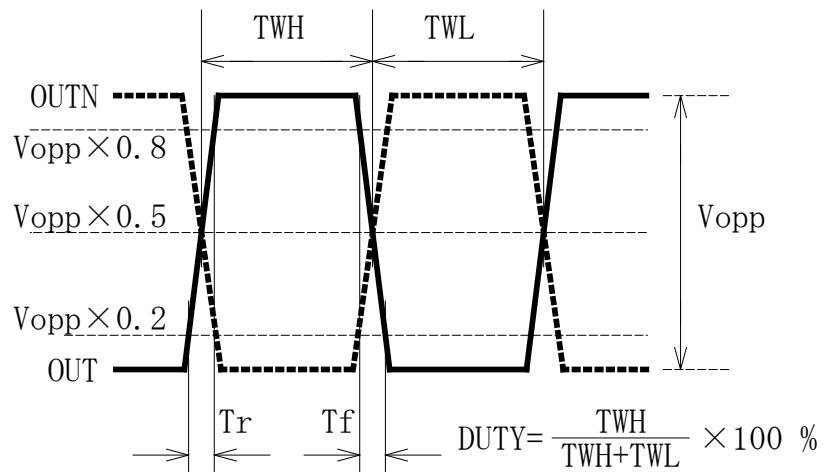


Fig. 5-2 Output Wave Form (Duty, Tr, Tf, VOPP) of pCML

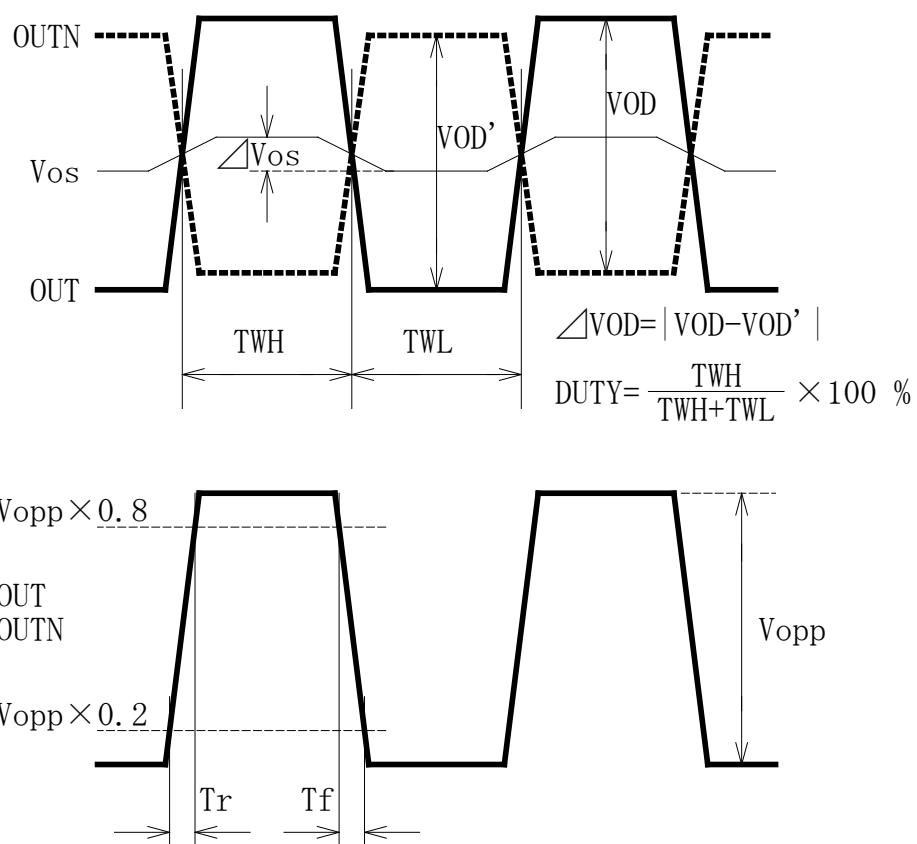
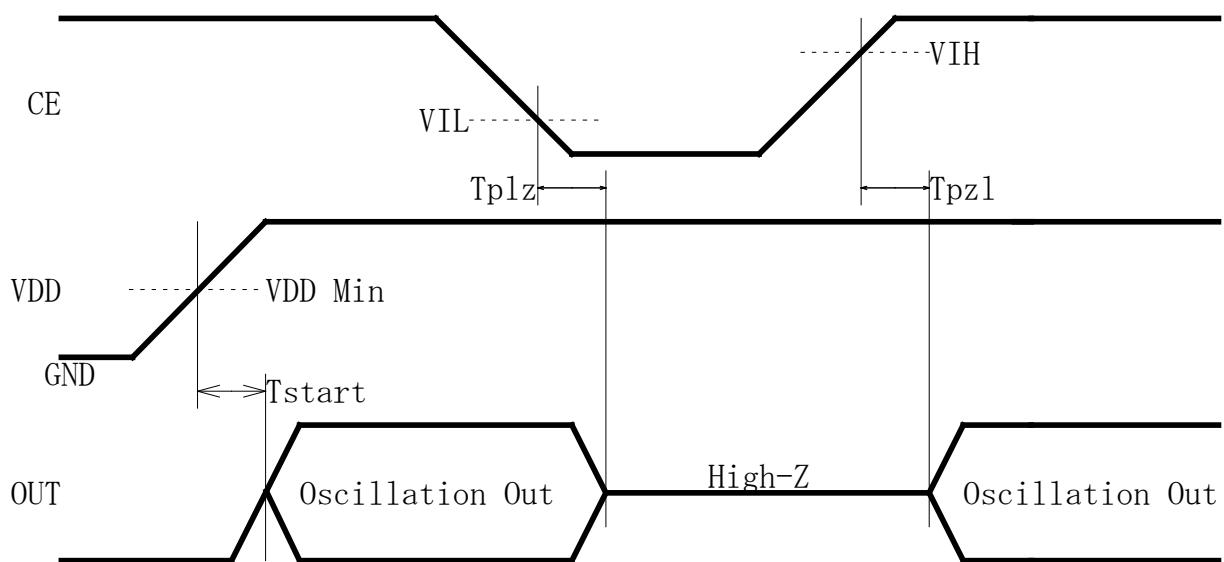


Fig. 5-3 Output Wave Form (Duty, Tr, Tf, VOH, VOL, VOD, Vos, Vopp) of LVDS



VIH : Threshold voltage for Oscillation Start
VIL : Threshold voltage for Oscillation Stop

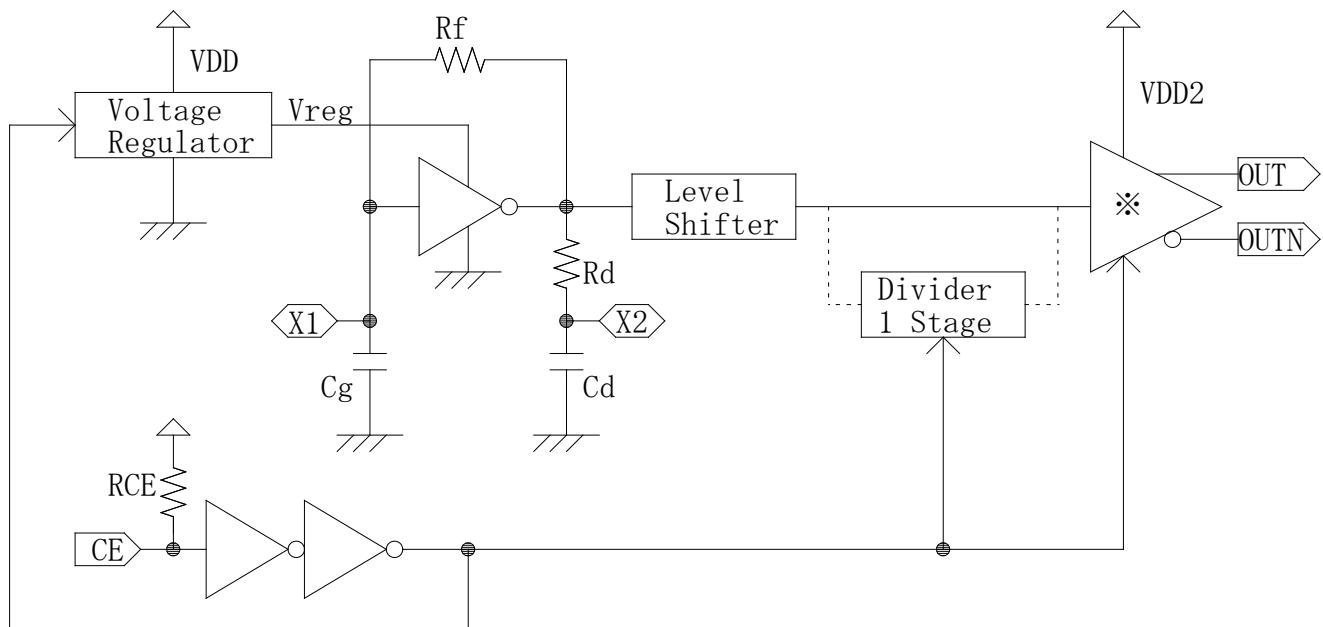
Fig. 5-4 Input output signal timing

6. Circuit Parameters of Oscillator (Reference Data for Circuit Design)

T_a=25°C

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Feedback Resistor	R _f	Refer to Fig. 6-1		200		kΩ
				200		
Driving Resistor	R _d	Refer to Fig. 6-1		157		Ω
				100		
Oscillation Capacitor	C _g	Refer to Fig. 6-1		6.0		pF
				8.0		
	C _g			3.0		
	C _d			7.0		

*The above values are the design values and are not guaranteed by test.

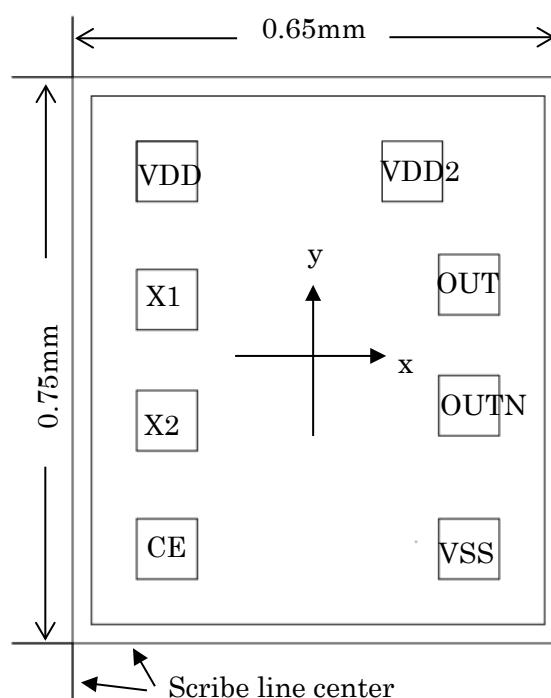


※ Output buffer according to each output waveform format

Fig. 6-1 Block Diagram

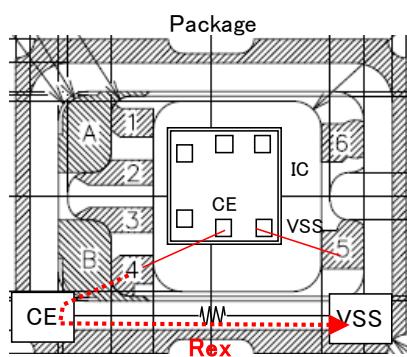
7. Pad Layout

7-1 Straight Type



- Die Size: 0.65mm × 0.75mm
- Pad Size: 80um □
- Thickness: 150um±20um
- IC Backside: Gnd or Open
- Swapping of OUT/OUTN with wire bond is acceptable

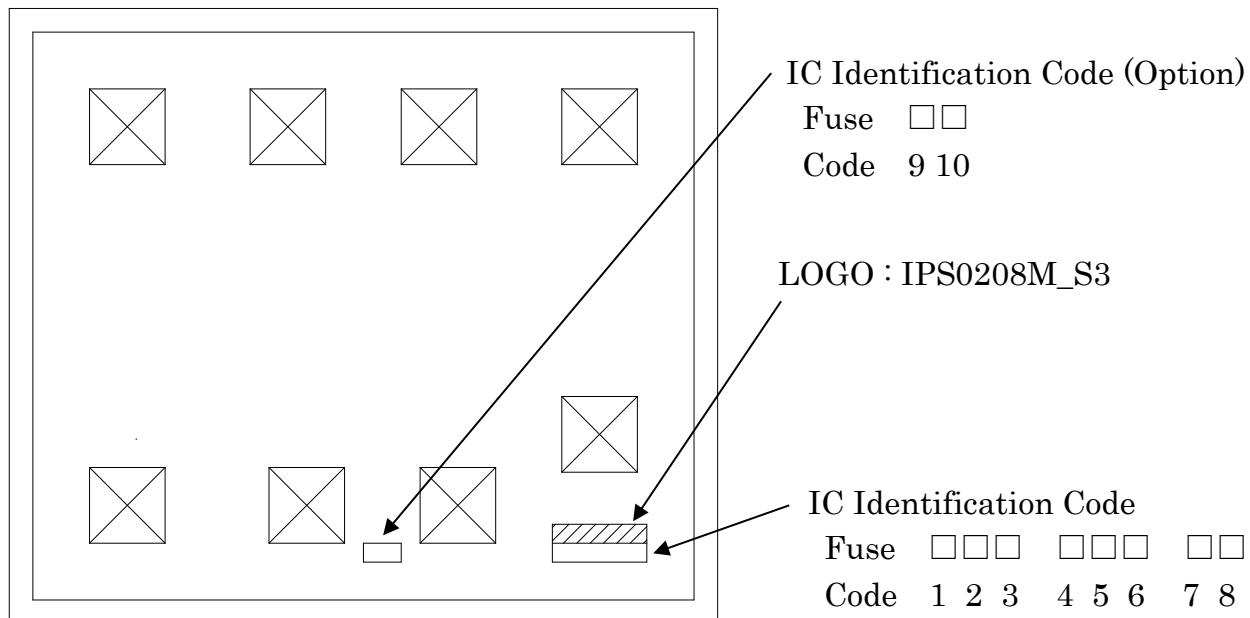
Pad Name	Function	Location (μm)	
		x	y
VDD	(+) Power Supply	-206	256
X1	Crystal Feedback	-206	83
X2	Crystal Drive	-206	-83
CE	Oscillation stop "L": High-Impedance	-206	-256
VSS	(-) Ground	206	-256
OUTN	OUT(Complementary)	206	-65
OUT	OUT(True)	206	108
VDD2	NC is acceptable	113	256
Chip Center		0	0



IMPORTANT Notice for CE function

- Oscillation will not be activated when CE=Open after CE=Low if Rex is not large.
- Reference value of Rex is over 10MΩ with CE=Open usage.
- There is no such issue with CE=VDD usage.

Rex : Resistance value between CE and VSS of package

8. IC Part # Identification
9.

IPS020*E series(High Freq.)

Part #	Code 1~8	Code 9, 10
IPS0208MOPEF	□□□□ □□□□ □□□	□□
IPS020DM0PES	□■□□ □□□□ □□□	□□
IPS0208MOPAEF	□□□□ □□□□ □□□	□■
IPS020DM0PAES	□■□□ □□□□ □□□	□■
IPS0208MODEF	□□□□ □□□□ □■□	□□
IPS020DM0DES	□■□□ □□□□ □■□	□□
IPS0208MOHES	□□□□ □□□□ ■□□	□□
IPS0208MOCES	□□□□ □□□□ ■■□	□□

□ : Fuse no cut

■ : Fuse cut